

Dkt.06080

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

PCT

WERNER BENCH

Serial No.: 10/586,946

Filed: July 25, 2006

For: SEMICONDUCTOR STRUCTURE COMPRISING ACTIVE ZONES

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

Sir:

Applicant submits herewith a Form PTO-1449 listing references for consideration by the Examiner, together with copies of non-U.S. patent references.

Respectfully submitted,

J. Schultz

Registration No. 28666

DENNISON, SCHULTZ & MACDONALD 1727 KING STREET LAW OFFICES

Sheet 1	of 1
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Form PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION E									ATTY DOCKET NO. 0608095		APPLICATION NO. 10/586,946			
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	5	1	6	6	7	6	1	04/1998	Kimura et al					
	5	7	3	9	5	5	2	11/1992	Olson et al					
	2002	1	6	7	0	1	4	11/2002	Schlereth et al					
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	0	7	2	7	\vdash	3	0	08/1996	EP					
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		Ozden et al, "A Dual-Wavelength Indium Gallium Nitride Quantum Well Light Emitting Diode", Applied Physics Letters 0003-6951, Vo. 79, No. 16, 2001, pp. 2532-2534.												
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